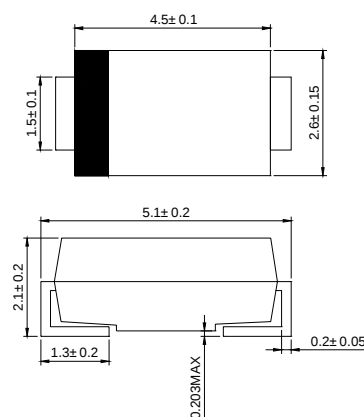


FEATURES

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-214AC, molded plastic
- ◇ Terminals: Solderable per MIL- STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.002 ounces, 0.064 grams
- ◇ Mounting position: Any

DO-214AC(SMA)


Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

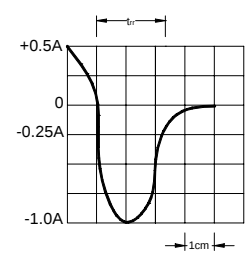
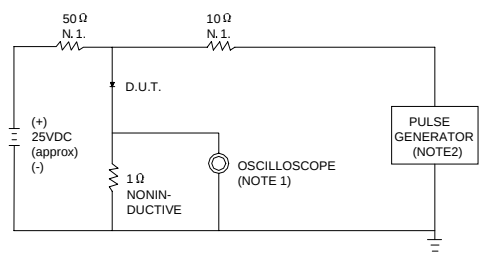
		ES1A	ES1B	ES1C	ES1D	ES1G	ES1H	ES1J	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	150	200	400	500	600	V
Maximum RMS voltage	V _{RMS}	35	70	105	140	280	350	420	V
Maximum DC blocking voltage	V _{DC}	50	100	150	200	400	500	600	V
Maximum average forward rectified current @T _A =75°C	I _{F(AV)}	1.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	30							A
Maximum instantaneous forward voltage at1.0 A	V _F	0.98		1.35		1.70			V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =125°C	I _R	5.0 200							μ A
Typical reverse recovery time (Note1)	t _{rr}	35							ns
Typical junction capacitance (Note2)	C _J	19					45		pF
Typical thermal resistance (Note3)	R _{θJA}	50							°C/W
Operating junction temperature range	T _J	- 55 ---- + 150							°C
Storage temperature range	T _{STG}	- 55 ---- + 150							°C

NOTE: 1. Measured with $I_F=0.5A$, $I_R=1A$, $t_{rr}=0.25A$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient and junction to lead P.C.B. mounted on 0.27"X0.27"(7.0X7.0mm2) copper pad areas

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = $1M\Omega$.22pF.
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω .

SET TIME BASE FOR 10/15 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

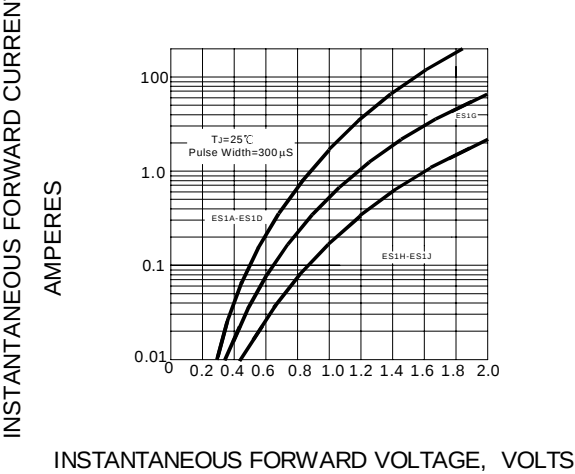


FIG.3 -- FORWARD DERATING CURVE

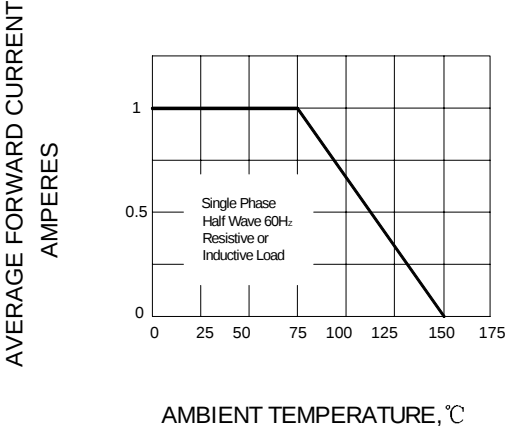


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

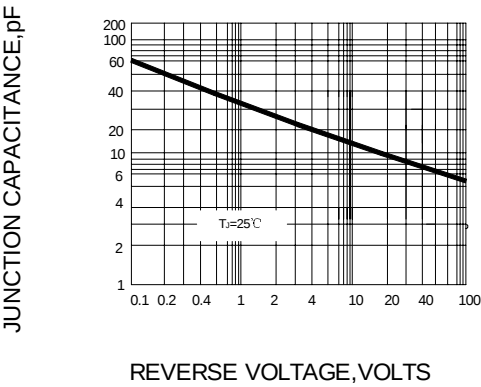


FIG.5 -- PEAK FORWARD SURGE CURRENT

